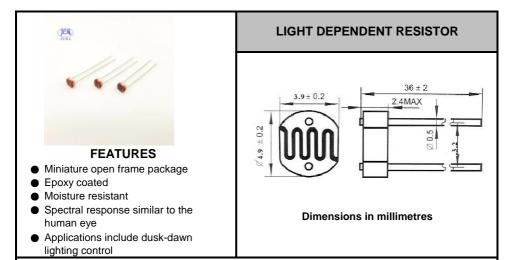


晶创和立科技

GL48537

MINIATURE CADMIUM SULPHIDE PHOTOCONDUCTIVE CELL



SPECIFICATION AND PERFORMANCE

Model	Vmax (VDC)	Pmax (mW)	Ambient temp(℃)	реак	Light Resistance at 10Lux (KΩ)	Dark Resistance (MΩ)	Gamm a value at 100- 10Lux	Response Time (ms)	
								Rise Time	Decay time
GL48537	150	90	-30~+70	540	20-30K	5	0.7	30	30

Measuring Conditions

1. Light resistance:

Measured at 10 Lux with standard light A (2854K color temperature) and 2hr illumination at 400-600 lux prior to testing. 2. Dark Resistance: Measured 10 senconds after closed 10 lux. 3. Gamma Characteristic:

Between 10 lux ande 100 lux and given by $\gamma = Ig(R10/R100)$ R10, R100 Cell resistance at 10 lux and

100 lux.

The error of γ is ± 0.1.

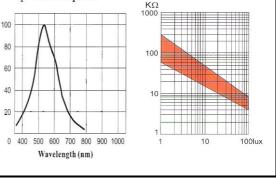
4. Pmax:

Max. power dissipation at ambient temperature of 25 $^\circ\!\!\mathbb{C}.$

5. Vmax:

Max. voltage in darkness that may be applied to the cell continuously.





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Relative Sensitivity (%